

Title (en)

METHOD AND DEVICE FOR PRODUCING SILICON

Title (de)

VERFAHREN UND VORRICHTUNG ZUR HERSTELLUNG VON SILIZIUM

Title (fr)

PROCÉDÉ ET DISPOSITIF POUR PRÉPARER DU SILICIUM

Publication

**EP 2203248 A1 20100707 (DE)**

Application

**EP 08840408 A 20081017**

Priority

- EP 2008064034 W 20081017
- DE 102007050010 A 20071017

Abstract (en)

[origin: WO2009050264A1] The present invention relates to a method for producing pure silicon from, for example, optionally doped quartz sand, by thermal reduction in a microwave oven.

IPC 8 full level

**B01J 19/12** (2006.01); **C01B 33/025** (2006.01); **C30B 13/00** (2006.01)

CPC (source: EP US)

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Citation (search report)

See references of WO 2009050264A1

Citation (examination)

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DOCDB simple family (publication)

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